NSN 5962-01-352-7917

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View Online at https://aerobasegroup.com/nsn/5962-01-352-7917

Body Length:
0.640 inches
Body Width:
Between 0.300 inches and 0.420 inches
Body Height:
Between 0.045 inches and 0.090 inches
Maximum Power Dissipation Rating:
1.04 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and hermetically sealed and burn in and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
F-6 mil-m-38510
Current Rating Per Characteristic:
190.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
15.00 input picofarads and 12.00 output picofarads
Time Rating Per Chacteristic:
40.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
24 flat leads
Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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